

## 1.0 SCOPE

This specification covers the detail requirements for a very low-noise quad operational amplifier.

It is highly recommended that this data sheet be used as a baseline for new military or aerospace spec control drawings.

## 1.2 Part Number. The complete part numbers per Table I of this specification follow:

<u>Device</u>	<u>Part Number</u>	<u>Package</u>
A	OP-470AY/883	Y
A	OP-470ATC/883	TC

### 1.2.3 Case Outline.

<u>Letter</u>	<u>Case Outline (Lead finish per MIL-M-38510)</u>
Y	14-lead ceramic dual-in-line package (CERDIP)
TC	28-contact hermetic leadless chip carrier (LCC)

## 1.3 Absolute Maximum Ratings. ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)

Supply Voltage.....	$\pm 18\text{V}$
Differential Input Voltage (Note 1).....	$\pm 1\text{V}$
Differential Input Current (Note 1).....	$\pm 25\text{mA}$
Input Voltage.....	Supply Voltage
Output Short-Circuit Duration .....	Continuous
Storage Temperature Range.....	-65°C to +150°C
Operating Temperature Range .....	-55°C to +125°C
Lead Temperature (Soldering, 60 sec).....	+300°C
Maximum Junction Temperature ( $T_J$ ).....	+150°C

### NOTES:

1. The OP-470's inputs are protected by back-to-back diodes. Current limiting resistors are not used in order to achieve low noise performance. If the differential input voltage exceeds  $\pm 1\text{V}$ , the input current should be limited to  $\pm 25\text{mA}$ .

12

## 1.5 Thermal Characteristics:

### Thermal Resistance, CERDIP (Y) package:

Junction-to-Case ( $\theta_{JC}$ ) = 29°C/W MAX

Junction-to Ambient ( $\theta_{JA}$ ) = 100°C/W MAX

### Thermal Resistance, LCC (TC) package:

Junction-to-Case ( $\theta_{JC}$ ) = 35°C/W MAX

Junction-to Ambient ( $\theta_{JA}$ ) = 110°C/W MAX

# OP-470

**TABLE 1**

$V_S = \pm 15V$ ;  $R_S = 50\Omega$ ;  $T_A = T_J = 25^\circ C$  unless otherwise specified.

Characteristics	Symbol	Special Conditions	OP-470/883		Units
			Min	Max	
<b>Input Offset Voltage</b>	$V_{OS}$	$V_{CM} = 0V$ $-55^\circ C \leq T_A \leq +125^\circ C$	—	0.4	mV
			—	0.6	mV
<b>Input Offset Current</b>	$I_{OS}$	$V_{CM} = 0V$ $V_{CM} = 0V$ $-55^\circ C \leq T_A \leq +125^\circ C$	—	10	nA
			—	20	nA
<b>Input Bias Current</b>	$I_B$	$V_{CM} = 0V$ $V_{CM} = 0V$ $-55^\circ C \leq T_A \leq +125^\circ C$	—	$\pm 25$	nA
			—	$\pm 50$	nA
<b>Input Noise Voltage</b>	$E_{nt}$	$f_O = 1Hz$ to $100Hz$ , see test circuit	—	110	nV <sub>RMS</sub>
<b>Large-Signal Voltage Gain</b>	$A_{VO}$	$V_O = \pm 10V$ , $R_L = 10k\Omega$ $V_O = \pm 10V$ , $R_L = 10k\Omega$ $-55^\circ C \leq T_A \leq +125^\circ C$	1000	—	V/mV
		$V_O = \pm 10V$ , $R_L = 2k\Omega$ $V_O = \pm 10V$ , $R_L = 2k\Omega$ $-55^\circ C \leq T_A \leq +125^\circ C$	750	—	V/mV
			500	—	V/mV
			400	—	V/mV
<b>Output Voltage Swing</b>	$V_O$	$R_L = 2k\Omega$ $R_L = 2k\Omega$ $-55^\circ C \leq T_A \leq +125^\circ C$	$\pm 12$	—	V
			$\pm 12$	—	V
<b>Common-Mode Rejection (Note 1)</b>	CMR	$V_{CM} = IVR = \pm 11V$ $V_{CM} = IVR = \pm 11V$ $-55^\circ C \leq T_A \leq +125^\circ C$	110	—	dB
			100	—	dB
<b>Power Supply Rejection Ratio</b>	PSRR	$V_S = \pm 4.5V$ to $\pm 18V$ $V_S = \pm 4.5V$ to $\pm 18V$ $-55^\circ C \leq T_A \leq +125^\circ C$	—	1.8	$\mu V/V$
			—	5.6	$\mu V/V$

TABLE 1 (Continued)

$V_S = \pm 15V$ ;  $R_S = 50\Omega$ ;  $T_A = T_J = 25^\circ C$  unless otherwise specified.

Characteristics	Symbol	Special Conditions	OP-470/883		Units
			Min	Max	
<b>Supply Current (Note 2)</b>	$I_{SY}$	No Load	—	11	mA
		No Load $-55^\circ C \leq T_A \leq +125^\circ C$	—	11	mA
<b>Slew Rate</b>	SR	$A_{VCL} = +20$ , $R_L = 10k\Omega$	$\pm 1.4$	—	V/ $\mu$ s

## NOTES:

1. IVR is defined as the  $V_{CM}$  range used for the CMR test.
2.  $I_{SY}$  limit = total all four amplifiers.

TABLE 2

## OP-470/883

**Electrical Test Requirements  
For Class B Devices**

12

MIL-STD-883 Test Requirements	Subgroups (see Table 3)
Interim Electrical Parameters (pre Burn-In)	1
Final Electrical Test Parameters	1*, 2, 3, 4, 5, 6
Group A Test Requirements	1, 2, 3, 4, 5, 6, 7

\* PDA applies to Subgroup 1 only.  
No other Subgroups are included in PDA.

TABLE 3

## Group A Inspection

 $V_S = \pm 15V; R_S = 50\Omega; T_A = T_J$  unless otherwise specified.

Subgroup	Symbol	Special Conditions	OP-470/883		Units
			Min	Max	
<b>Subgroup 1</b>	$V_{OS}$		-	0.4	mV
$T_A = +25^\circ C$	$I_{OS}$	$V_{CM} = 0V$	-	10	nA
	$I_B$	$V_{CM} = 0V$	-	$\pm 25$	nA
	CMR	$V_{CM} = \pm 11V$	110	-	dB
	PSRR	$V_S = \pm 4.5V, \pm 18V$	-	1.8	$\mu V/V$
	$I_{SY}$	No Load (Note 1)	-	11	mA
<b>Subgroup 2</b>	$V_{OS}$		--	0.6	mV
$T_A = +125^\circ C$	$I_{OS}$	$V_{CM} = 0V$	--	20	nA
	$I_B$	$V_{CM} = 0V$	-	$\pm 50$	nA
	CMR	$V_{CM} = \pm 11V$	100	-	dB
	PSRR	$V_S = \pm 4.5V, \pm 18V$	--	5.6	$\mu V/V$
	$I_{SY}$	No Load (Note 1)	-	11	mA
<b>Subgroup 3</b>	All Tests, Limits and Conditions are the same as for Subgroup 2.				
$T_A = -55^\circ C$					
<b>Subgroup 4</b>	$A_{VO}$	$V_O = \pm 10V, R_L = 10k\Omega$	1000	--	$V/mV$
$T_A = +25^\circ C$		$V_O = \pm 10V, R_L = 2k\Omega$	500	--	$V/mV$
	$V_O$	$R_L = 2k\Omega$	$\pm 12$	-	V

TABLE 3

## Group A Inspection (Continued)

 $V_S = \pm 15V$ ;  $R_S = 50\Omega$ ;  $T_A = T_J$  unless otherwise specified.

Subgroup	Symbol	Special Conditions	OP-470/883		Units
			Min	Max	
Subgroup 5  $T_A = +125^\circ C$	$A_{VO}$	$V_O = \pm 10V, R_L = 10k\Omega$	750	—	V/mV
		$V_O = \pm 10V, R_L = 2k\Omega$	400	—	V/mV
	$V_O$	$R_L = 2k\Omega$	$\pm 12$	—	V
Subgroup 6  $T_A = -55^\circ C$	All Tests, Limits and Conditions are the same as for Subgroup 5.				
Subgroup 7  $T_A = +25^\circ C$	SR	$A_{VCL} = +20, R_L = 10k\Omega$	$\pm 1.4$	—	V/ $\mu$ s
	$E_{nt}$	$f_O = 1Hz$ to $100Hz$ , see test circuit	—	110	nV <sub>RMS</sub>

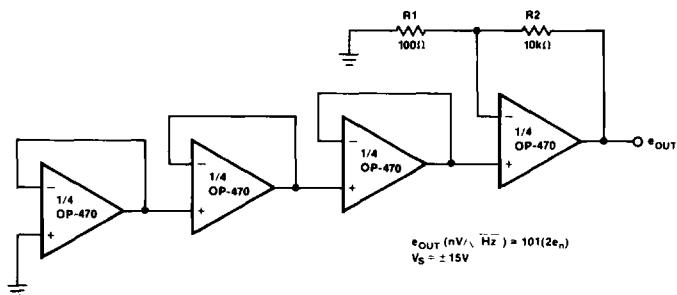
## NOTES:

1.  $I_{SY}$  limit = total all four amplifiers.

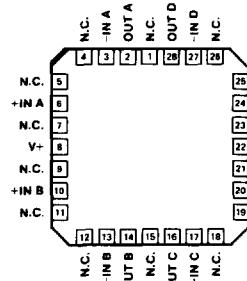
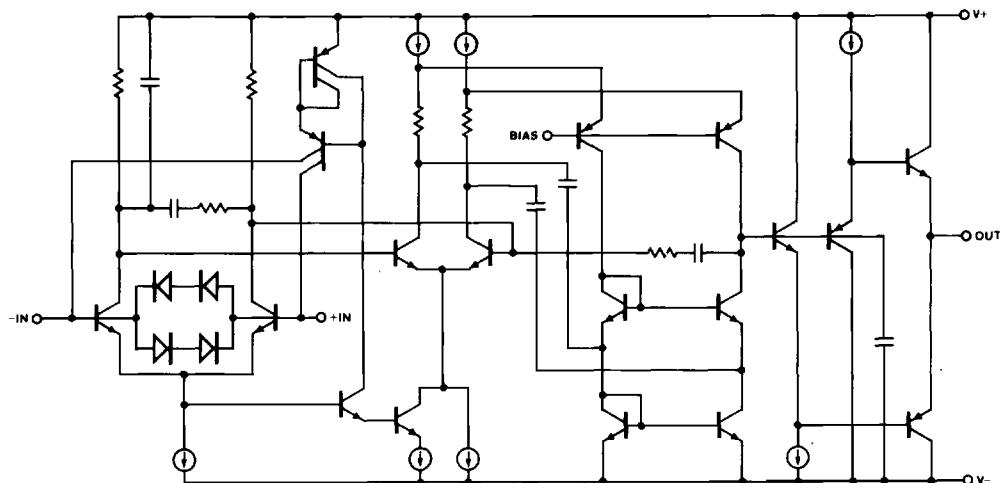
12

# OP-470

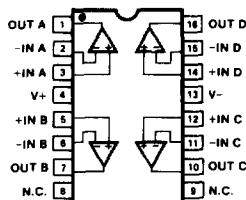
## Noise Voltage Density Test Circuit



### 3.2.1 Simplified Schematic and Pin Connections.



28-LEAD LCC  
(TC-Suffix)



14-PIN HERMETIC DIP  
(Y-Suffix)

3.2.4 Microcircuit Group Assignment. This microcircuit is covered by microcircuit group 49.

#### 4.2 Life Test/Burn-In Circuit.

